Medium power transistor (-32V, -2A) 2SB1188 / 2SB1182 / 2SB1240

Features

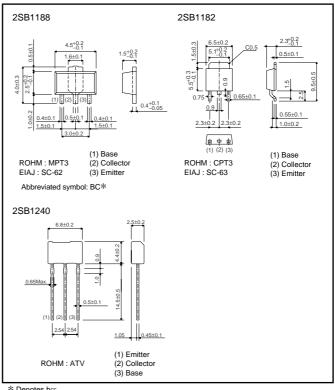
1) Low VCE(sat). $V_{CE(sat)} = -0.5V (Typ.)$ (Ic/IB = -2A/-0.2A)

2) Complements the 2SD1766 / 2SD1758 / 2SD1862.

Structure

Epitaxial planar type PNP silicon transistor

●External dimensions (Unit : mm)



^{*} Denotes her

● Absolute maximum ratings (Ta=25°C)

| Parameter | | Symbol | Limits | Unit | |
|-----------------------------|---------|--------|------------|-------------|--|
| Collector-base voltage | | Vсво | -40 | V | |
| Collector-emitter voltage | | Vceo | -32 | V | |
| Emitter-base voltage | | Vево | -5 | V | |
| Collector current | | | -2 | A(DC) | |
| | | lc | -3 | A (Pulse)*1 | |
| Collector power dissipation | 2SB1188 | - Pc | 0.5 | W | |
| | | | 2 | W *2 | |
| | 2SB1182 | | 10 | W (Tc=25°C) | |
| | 2SB1240 | | 1 | W *3 | |
| Junction temperature | | Tj | 150 | °C | |
| Storage temperature | | Tstg | -55 to 150 | °C | |

^{*1} Single pulse, Pw=100ms

^{*3} Printed circuit board, 1.7mm thick, collector copper plating 100mm² or larger.



^{*2} When mounted on a 40×40×0.7 mm ceramic board.

●Electrical characteristics (Ta=25°C)

| Parameter | Symbol | Min. | Тур. | Max. | Unit | Conditions | |
|--------------------------------------|----------|------|------|------|------|--------------------------------|---|
| Collector-base breakdown voltage | ВУсво | -40 | _ | _ | V | Ic= -50μA | |
| Collector-emitter breakdown voltage | BVceo | -32 | _ | _ | V | Ic= -1mA | |
| Emitter-base breakdown voltage | ВУево | -5 | _ | _ | V | Iε= -50μA | |
| Collector cutoff current | Ісво | _ | _ | -1 | μΑ | VcB= -20V | |
| Emitter cutoff current | ІЕВО | - | _ | -1 | μΑ | V _{EB} = -4V | |
| Collector-emitter saturation voltage | VCE(sat) | _ | -0.5 | -0.8 | V | Ic/I _B = -2A/ -0.2A | * |
| DC current transfer ratio | hfe | 82 | _ | 390 | _ | Vce= -3V, Ic= -0.5A | * |
| Transition frequency | f⊤ | _ | 100 | _ | MHz | Vce= -5V, Ie=0.5A, f=100MHz | |
| Output capacitance | Cob | _ | 50 | _ | pF | Vcb= -10V, IE=0A, f=1MHz | |

^{*} Measured using pulse current.

●Packaging specifications and hFE

| | | Package | Taping | | | | |
|---------|-----|------------------------------|--------|------|------|---|---|
| | | Code | T100 | TL | TV2 | | |
| Туре | hfe | Basic ordering unit (pieces) | 1000 | 2500 | 2500 | | |
| 2SB1188 | PQR | | 0 | - | - | | |
| 2SB1182 | PQR | | PQR | | - | 0 | - |
| 2SB1240 | PQR | | - | _ | 0 | | |

hre values are classified as follows:

| Item | Р | Q | R |
|------|-----------|------------|------------|
| hfe | 82 to 180 | 120 to 270 | 180 to 390 |

•Electrical characteristic curves

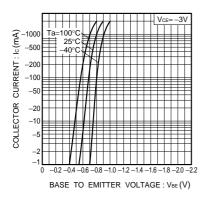


Fig.1 Grounded emitter propagation characteristics

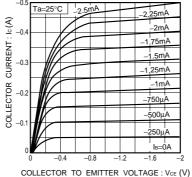


Fig.2 Grounded emitter output characteristics

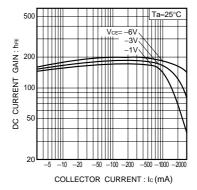


Fig.3 DC current gain vs. collector curren (I)

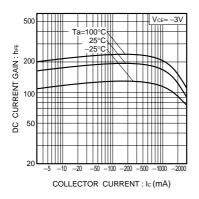


Fig.4 DC current gain vs. collector current (II)

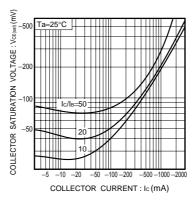


Fig.5 Collector-emitter saturation voltage vs. collector current (I)

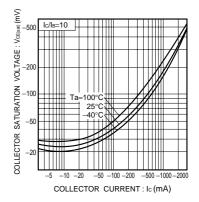


Fig.6 Collector-emitter saturation voltage vs. collector current (II)

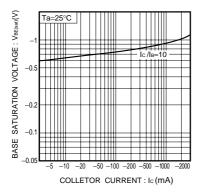


Fig.7 Base-emitter saturation voltage vs. collector current

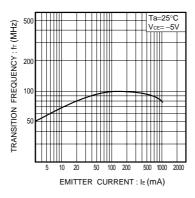


Fig.8 Gain bandwidth product vs. emitter current

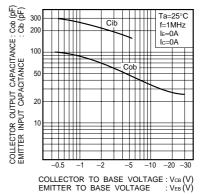


Fig.9 Collector output capacitance vs. collector-base voltage Emitter input capacitance vs. emitter-base voltage

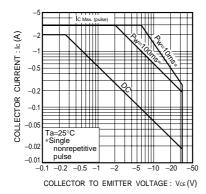


Fig.10 Safe operation area (2SB1188)

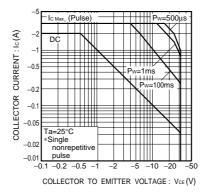


Fig.11 Safe operation area (2SB1182)

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